

**AMENDMENTS TO THE CLAIMS**

1. (Previously Presented) A method of analyzing a waveform of a source current in a semiconductor integrated circuit including a digital circuit having a plurality of logic gates, comprising:

representing the digital circuit, according to a distribution of switching operations of the logic gates in the digital circuit, as a time-division group of parasitic capacitors comprising parasitic capacitors each connected between a source line and a ground line to be charged at a specific timing, and a group of parasitic capacitors each charged statically;

generating an analysis model by coupling one end of the time-division group of parasitic capacitors, one end of the group of parasitic capacitors charged statically, and parasitic impedance of the source line, and connecting the other end of the time-division group of parasitic capacitors, the other end of the group of parasitic capacitors charged statically, and parasitic impedance of the ground line; and

determining the waveform of the source current in the digital circuit from the analysis model.

2. (Currently Amended) The method according to claim 1, wherein the digital circuit is divided into a plurality of segments along ~~the~~a border at which the parasitic impedances of the source line and the ground line are locally increased, the time-division group of parasitic capacitors and the group of the parasitic capacitors statically charged are assigned for a group of the logic gates included in each segment.

3. (Currently Amended) The method according to claim 1, wherein each parasitic capacitor

included in the time-division group of parasitic capacitors is determined every predetermined time interval, and wherein ~~the~~ a length of the time interval is set according to a frequency of the switching operations of the logic gates in a period of time at which the parasitic capacitors are determined.

4. (Original) The method according to claim 3, wherein the length of the time interval is set to be of shorter as the frequency of the switching operations is greater.

5. (Currently Amended) The method according to claim 1, wherein a capacitance of the parasitic capacitor to be charged at a specific timing is calculated from input and output capacitance of the logic gates in the digital circuit to be analyzed.

6. (Original) A method of analyzing a substrate noise comprising:  
regarding, as a substrate noise, a change in voltage which is caused by an interaction between the source current in the digital circuit determined from the analysis model and the parasitic impedances of the source line and the ground line; and  
using the method of claim 1 with the regarded change in voltage to analyze the substrate noise.

7. (Currently Amended) A method of designing a semiconductor integrated circuit which includes analog and digital circuits, comprising:  
receiving ~~the~~ a design specification;  
designing the analog and digital circuits according to the design specification;

analyzing a substrate noise generated in the digital circuits using the method of claim 6; and  
re-designing the analog and digital circuits or their layout and the location of guard bands by  
reviewing ~~the~~a result of the substrate noise analysis so that ~~the~~a design specification is satisfied.

8. (Previously Presented) An apparatus for analyzing a waveform of a source current in a  
semiconductor integrated circuit including a digital circuit having a plurality of logic gates,  
comprising:

arrangement for representing the digital circuit, according to a distribution of switching  
operations of the logic gates in the digital circuit, as a time-division group of parasitic capacitors  
comprising parasitic capacitors each connected between a source line and a ground line to be  
charged at a specific timing, and a group of parasitic capacitors each charged statically;

arrangement for generating an analysis model by coupling one end of the time-division  
group of parasitic capacitors, one end of the group of parasitic capacitors charged statically, and  
parasitic impedance of the source line, and connecting the other end of the time-division group of  
parasitic capacitors, the other end of the group of parasitic capacitors charged statically, and  
parasitic impedance of the ground line; and

arrangement for determining the waveform of the source current in the digital circuit from  
the analysis model.

9. (Currently Amended) The apparatus according to claim 8, wherein the digital circuit is  
divided into a plurality of segments along ~~the~~a border at which the parasitic impedances of the  
source line and the ground line are locally increased, the time-division group of parasitic capacitors  
and the group of the parasitic capacitors ~~statically~~statically charged statically are assigned for a group of the

logic gates included in each segment

10. (Currently Amended)) The apparatus according to claim 8, wherein each parasitic capacitor included in the time-division group of parasitic capacitors is determined every predetermined time interval, and wherein ~~the~~ a length of the time interval is set according to a frequency of the switching operations of the logic gates in a period of time at which the parasitic capacitors are determined.

11. (Original) The apparatus according to claim 10, wherein the length of the time interval is set to be of shorter as the frequency of the switching operations is greater.

12. (Currently Amended) The apparatus according to claim 8, wherein a capacitance of the parasitic capacitor to be charged at a specific timing is calculated from input and output capacitance of the logic gates in the digital circuit to be analyzed.

13. (New) The method according to claim 1, wherein each capacitor of the time-division group of parasitic capacitors is charged at different times in accordance with a predetermined time interval.

14. (New) The apparatus according to claim 8, wherein each capacitor of the time-division group of parasitic capacitors is charged at different times in accordance with a predetermined time interval.